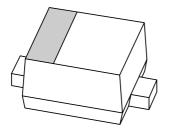
DISCRETE SEMICONDUCTORS

DATA SHEET



BAP1321-01Silicon PIN diode

Preliminary specification

2001 Nov 01





Silicon PIN diode BAP1321-01

FEATURES

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Very low series inductance
- For applications up to 3 GHz.

APPLICATIONS

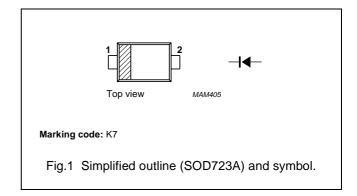
• RF attenuators and switches.

DESCRIPTION

Planar PIN diode in a SOD723A ultra small plastic SMD package.

PINNING

PIN	DESCRIPTION
1	cathode
2	anode



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	60	V
I _F	continuous forward current		_	100	mA
P _{tot}	total power dissipation	T _s = 90 °C	_	315	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

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ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
V _F	forward voltage	I _F = 50 mA	0.95	1.1	V
I _R	reverse leakage current	V _R = 60 V	_	0.1	μΑ
		V _R = 20 V	_	tbd	μΑ
C _d	diode capacitance	V _R = 0; f = 1 MHz	0.32	_	pF
		$V_R = 1 V$; $f = 1 MHz$	0.28	_	pF
		$V_R = 20 \text{ V}; f = 1 \text{ MHz}$	0.22	0.32	pF
r_D	diode forward resistance	f = 100 MHz; note 1			
		$I_F = 0.5 \text{ mA}$	3.2	5.0	Ω
		I _F = 1 mA	2.3	3.6	Ω
		I _F = 10 mA	1.1	1.8	Ω
		I _F = 100 mA	8.0	1.3	Ω
S ₂₁ ²	isolation	V _R = 0; f = 900 MHz	15.7	_	dB
		V _R = 0; f = 1800 MHz	10.8	-	dB
		V _R = 0; f = 2450 MHz	8.7	_	dB
S ₂₁ ²	insertion loss	$I_F = 0.5 \text{ mA}; f = 900 \text{ MHz}$	0.26	_	dB
		$I_F = 0.5 \text{ mA}$; $f = 1800 \text{ MHz}$	0.28	_	dB
		$I_F = 0.5 \text{ mA}; f = 2450 \text{ MHz}$	0.31	_	dB
S ₂₁ ²	insertion loss	I _F = 1 mA; f = 900 MHz	0.20	_	dB
		$I_F = 1 \text{ mA}; f = 1800 \text{ MHz}$	0.23	_	dB
		$I_F = 1 \text{ mA}$; $f = 2450 \text{ MHz}$	0.25	_	dB
s ₂₁ ²	insertion loss	$I_F = 10 \text{ mA}; f = 900 \text{ MHz}$	0.15	_	dB
		$I_F = 10 \text{ mA}; f = 1800 \text{ MHz}$	0.18	_	dB
		$I_F = 10 \text{ mA}; f = 2450 \text{ MHz}$	0.21	_	dB
S ₂₁ ²	insertion loss	$I_F = 100 \text{ mA}; f = 900 \text{ MHz}$	0.10	_	dB
		$I_F = 100 \text{ mA}; f = 1800 \text{ MHz}$	0.13	_	dB
		$I_F = 100 \text{ mA}; f = 2450 \text{ MHz}$	0.16	_	dB
$ au_{L}$	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω ; measured at I_R = 3 mA	0.5	_	μs
L _S	series inductance	I _F = 100 mA; f = 100 MHz	0.6	_	nH

Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point		K/W

Silicon PIN diode

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GRAPHICAL DATA

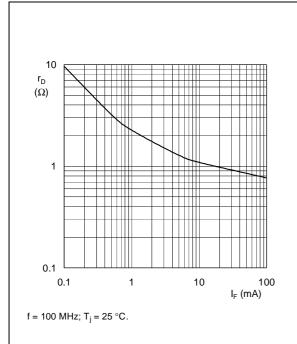


Fig.2 Forward resistance as a function of forward current; typical values.

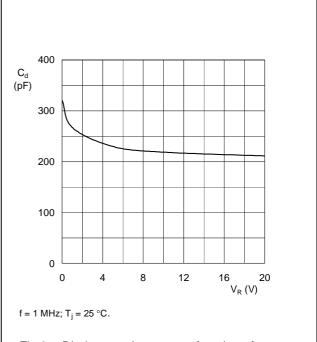
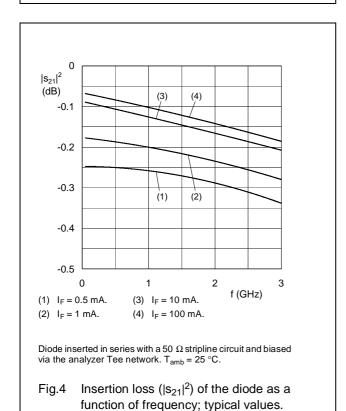
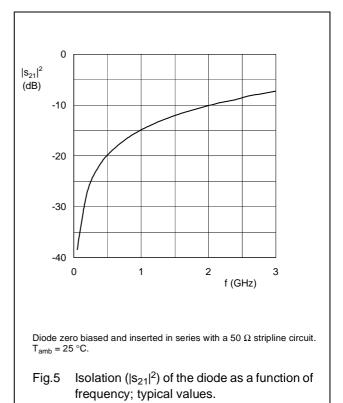


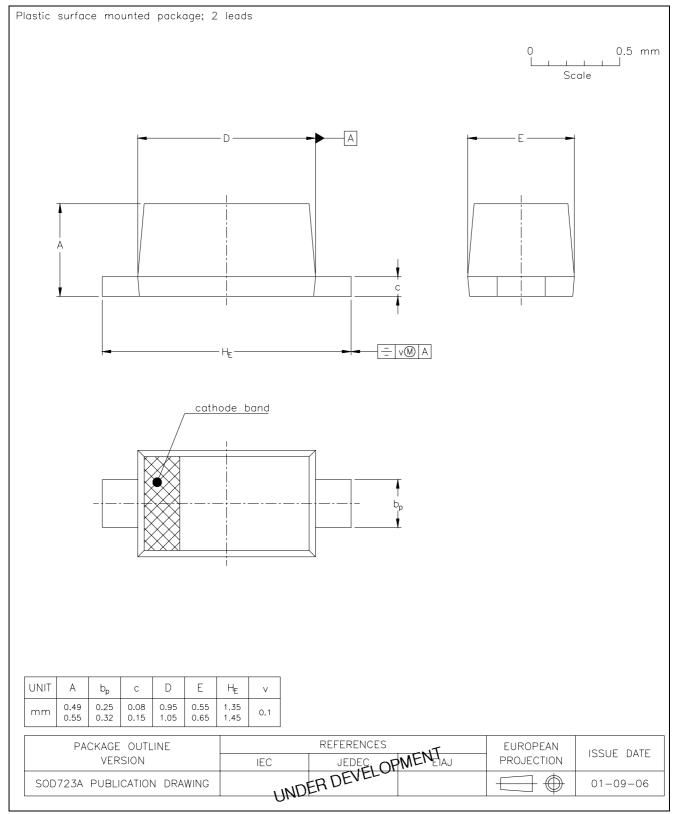
Fig.3 Diode capacitance as a function of reverse voltage; typical values.





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PACKAGE OUTLINE SOD723A



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DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
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Printed in The Netherlands

603504/05/pp7

Date of release: 2001 Nov 01

Document order number: 9397 750 08975

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